N-Channel 150 V (D-S) MOSFET

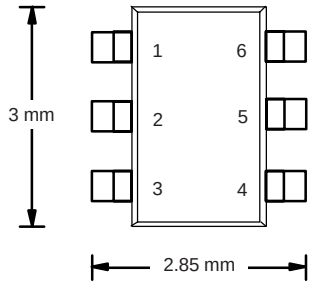
PRODUCT SUMMARY			
V_{DS} (V)	$R_{DS(on)}$ (Ω)	I_D (A)[a, e]	Q_g (Typ.)
150	0.340 at V_{GS} = 10 V	2	3.2 nC
	0.360 at V_{GS} = 6 V	1	

FEATURES

- DT-Trench Power MOSFET
- Low On-Resistance
- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC

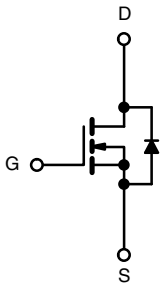
Pb-free
RoHS COMPLIANT

SOT-23-6
Top View



APPLICATIONS

- DC/DC Converters, High Speed Switching



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)				
Parameter		**Symbol**	**Limit**	**Unit**
Drain-Source Voltage		V_{DS}	150	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current (T_J = 150 °C)	T_C = 25 °C	I_D	2[e]	A
	T_C = 70 °C		1.6 [e]	
	T_A = 25 °C		1.3[b, c]	
	T_A = 70 °C		1.0[b, c]	
Pulsed Drain Current (t = 100 µs)		I_{DM}	8	
Continuous Source-Drain Diode Current	T_C = 25 °C	I_S	2.0	
	T_A = 25 °C		1.0[b, c]	
Maximum Power Dissipation	T_C = 25 °C	P_D	1.2	W
	T_C = 70 °C		0.4	
	T_A = 25 °C		1.2[b, c]	
	T_A = 70 °C		0.6[b, c]	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	- 55 to 150	°C
Soldering Recommendations (Peak Temperature)			230	

THERMAL RESISTANCE RATINGS					
Parameter		**Symbol**	**Typical**	**Maximum**	**Unit**
Maximum Junction-to-Ambient[b, d]	t ≤ 5 s	R_{thJA}	75	100	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	40	50	

Notes:
a. Based on T_C = 25 °C.
b. Surface mounted on 1" x 1" FR4 board.
c. t = 5 s.
d. Maximum under steady state conditions is 166 °C/W.
e. Package limited.

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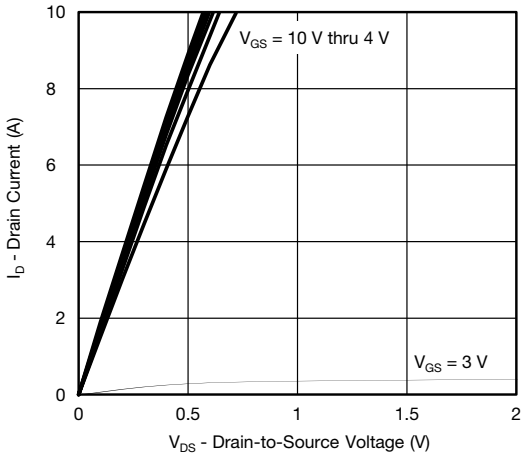
SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)						
Parameter	**Symbol**	**Test Conditions**	**Min.**	**Typ.**	**Max.**	**Unit**
Static						
Drain-Source Breakdown Voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA	150			V
V_{DS} Temperature Coefficient	$\Delta V_{DS}/T_J$	I_D = 250 µA		30		mV/°C
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$			- 4.8		
Gate-Source Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS} , I_D = 250 µA	2.0		4.0	V
Gate-Source Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 150 V, V_{GS} = 0 V			1	µA
		V_{DS} = 120 V, V_{GS} = 0 V, T_J = 70 °C			10	
On-State Drain Current[a]	$I_{D(on)}$	V_{DS} ≤ 5 V, V_{GS} = 10 V	10			A
Drain-Source On-State Resistance[a]	$R_{DS(on)}$	V_{GS} =10 V, I_D = 1.5 A		0.340		Ω
		V_{GS} =6 V, I_D = 1 A		0.360		
Forward Transconductance[a]	g_{fs}	V_{DS} = 15 V, I_D = 1.5 A		13		S
Dynamic[b]						
Input Capacitance	C_{iss}	V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz		500		pF
Output Capacitance	C_{oss}			150		
Reverse Transfer Capacitance	C_{rss}			50		
Total Gate Charge	Q_g	V_{DS} = 15 V, V_{GS} = 10 V, I_D = 1.5 A		8.0		nC
		V_{DS} = 15 V, V_{GS} = 4.5 V, I_D = 1.5 A		3.9		
Gate-Source Charge	Q_{gs}			1.2		
Gate-Drain Charge	Q_{gd}			1.2		
Gate Resistance	R_g	f = 1 MHz	2.5	12.6	25.2	Ω
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = 15 V, R_L = 3.4 Ω I_D ≅ 1.4 A, V_{GEN} = 4.5 V, R_g = 1 Ω		5		ns
Rise Time	t_r			16		
Turn-Off Delay Time	$t_{d(off)}$			12		
Fall Time	t_f			9		
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = 15 V, R_L = 3.4 Ω I_D ≅ 1.4 A, V_{GEN} = 10 V, R_g = 1 Ω		4		
Rise Time	t_r			8		
Turn-Off Delay Time	$t_{d(off)}$			17		
Fall Time	t_f			6		
Drain-Source Body Diode Characteristics						
Continuous Source-Drain Diode Current	I_S	T_C = 25 °C			2.1	A
Pulse Diode Forward Current	I_{SM}				10	
Body Diode Voltage	V_{SD}	I_S = 1.4 A, V_{GS} =0 V		0.82	1.2	V
Body Diode Reverse Recovery Time	t_{rr}	I_F = 1.4 A, dI/dt = 10 A/µs, T_J = 25 °C		13	20	ns
Body Diode Reverse Recovery Charge	Q_{rr}			6	12	nC
Reverse Recovery Fall Time	t_a			8		ns
Reverse Recovery Rise Time	t_b			5		

Notes:
a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
b. Guaranteed by design, not subject to production testing.

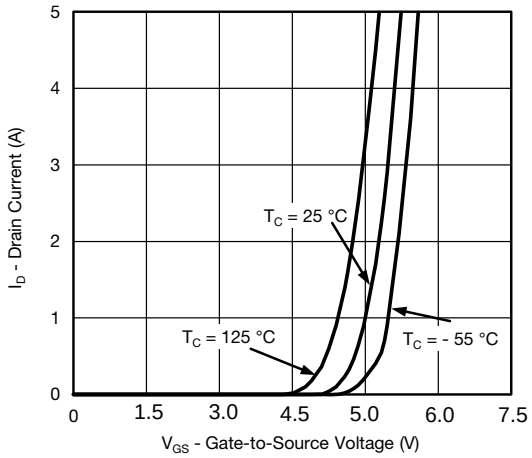
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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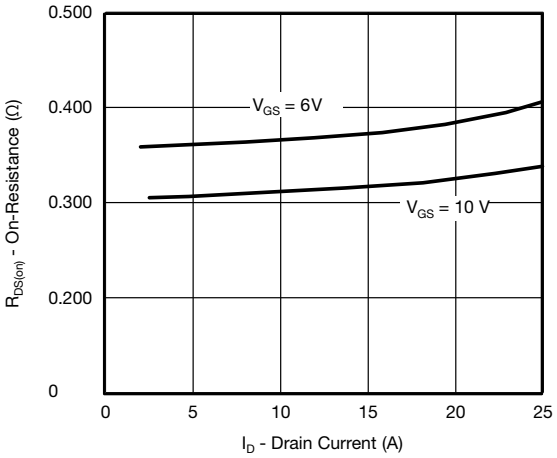
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



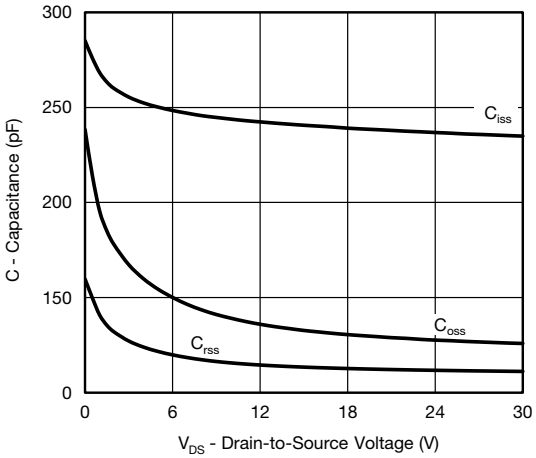
Output Characteristics



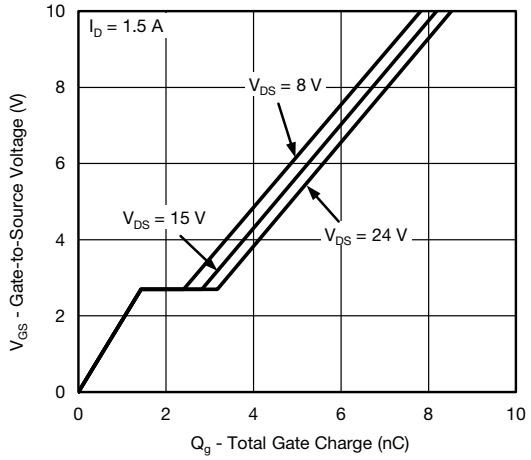
Transfer Characteristics



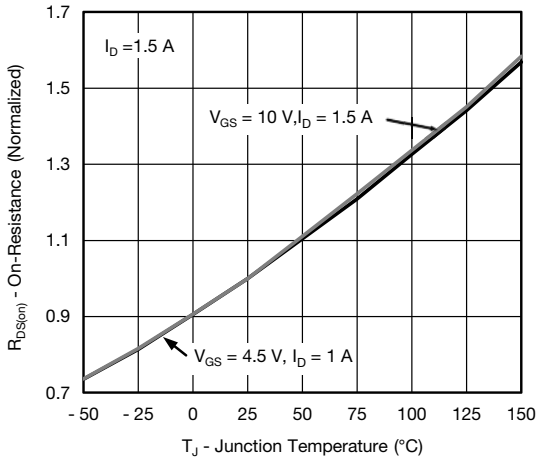
On-Resistance vs. Drain Current and Gate Voltage



Capacitance



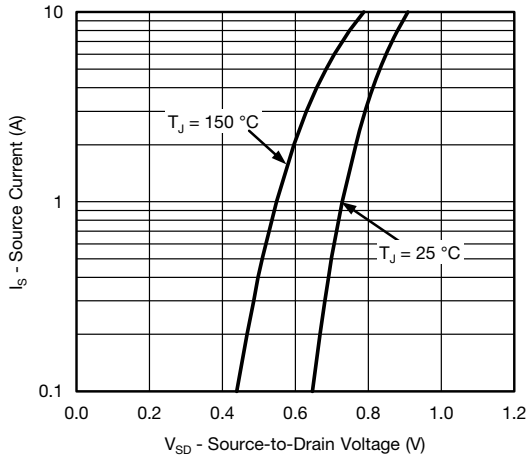
Gate Charge



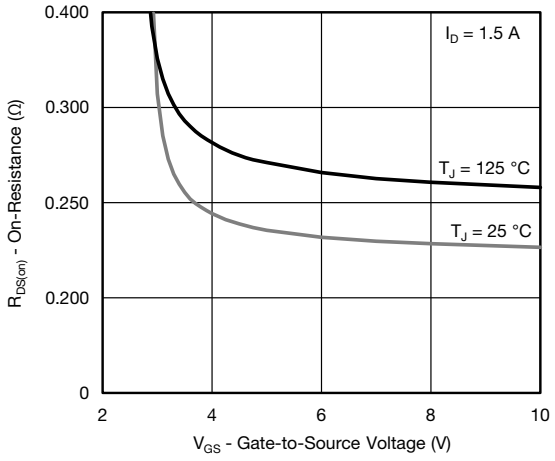
On-Resistance vs. Junction Temperature

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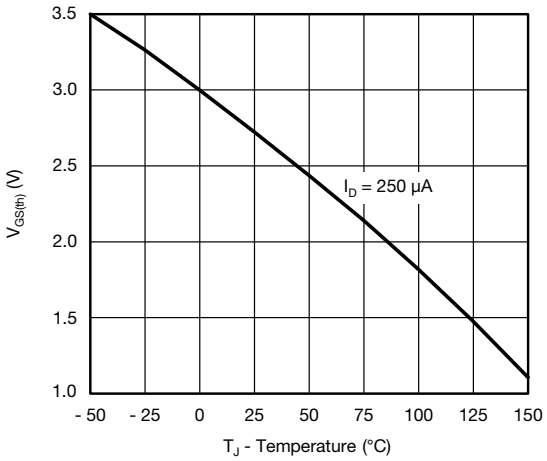
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



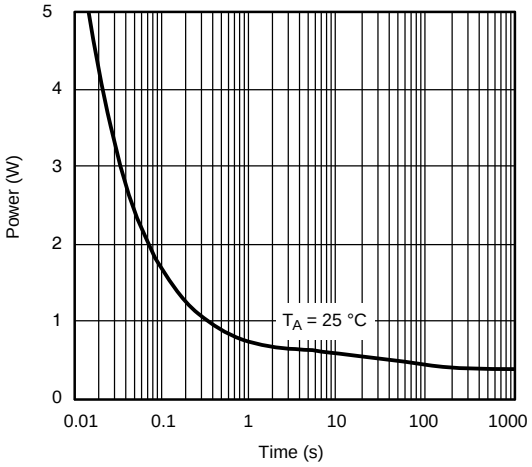
Source-Drain Diode Forward Voltage



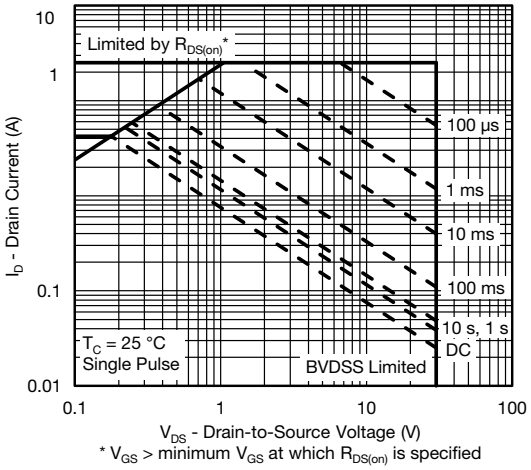
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



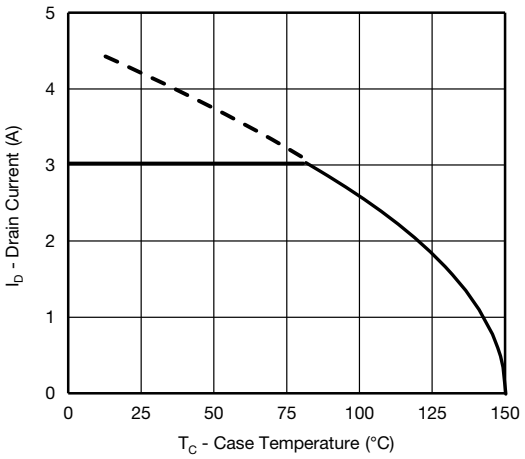
Single Pulse Power (Junction-to-Ambient)



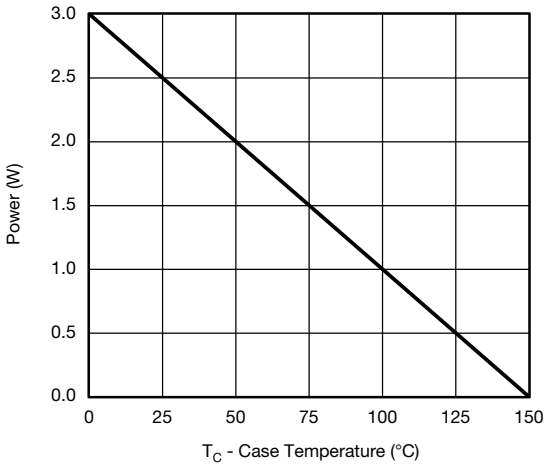
Safe Operating Area, Junction-to-Ambient

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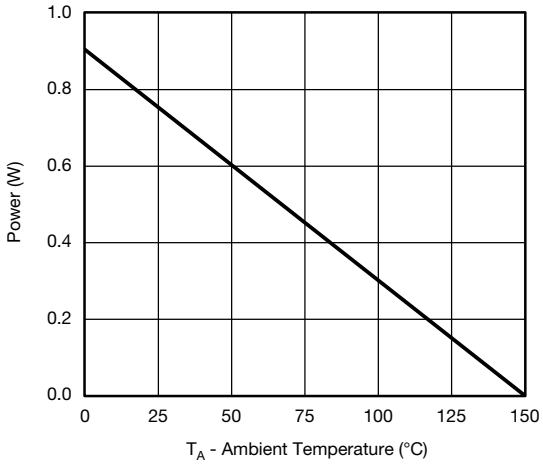
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating*



Power Derating, Junction-to-Foot

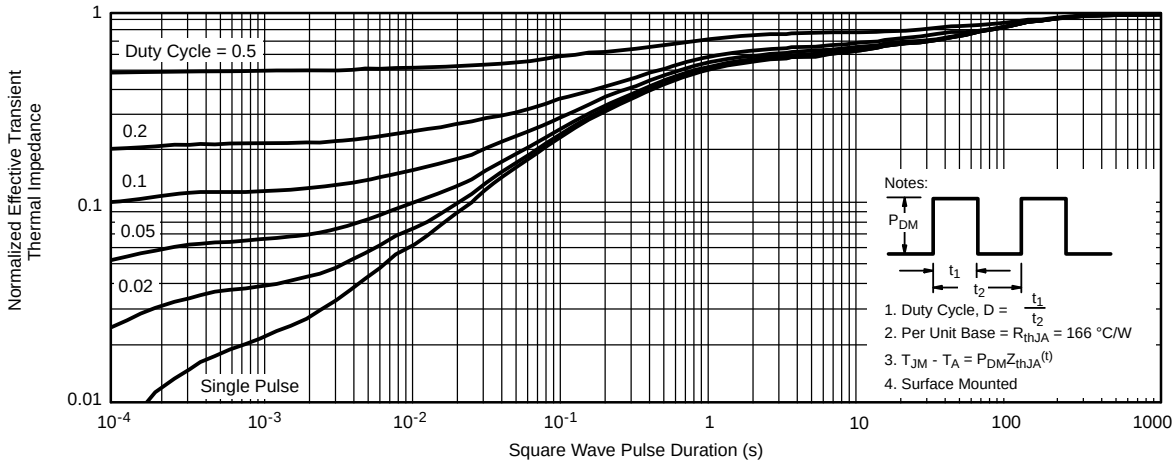


Power Derating, Junction-to-Ambient

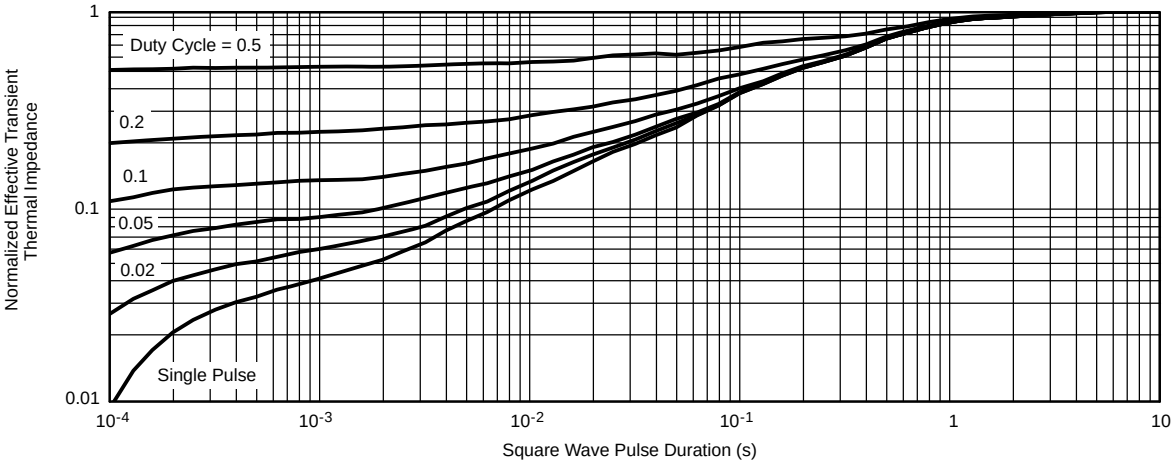
* The power dissipation P_D is based on $T_{J(max.)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



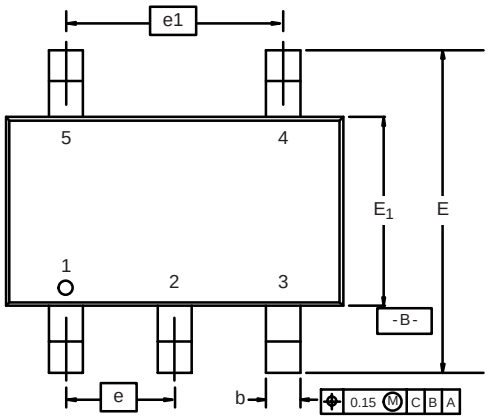
Normalized Thermal Transient Impedance, Junction-to-Ambient



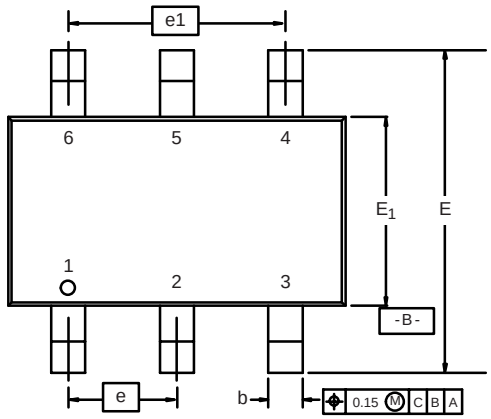
Normalized Thermal Transient Impedance, Junction-to-Foot

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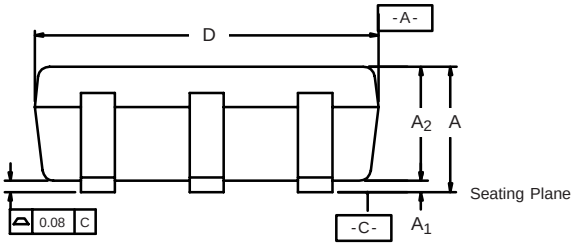
TSOP: 5/6−LEAD
JEDEC Part Number: MO-193C

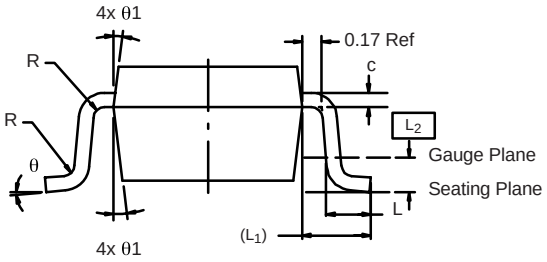


5-LEAD TSOP



6-LEAD TSOP

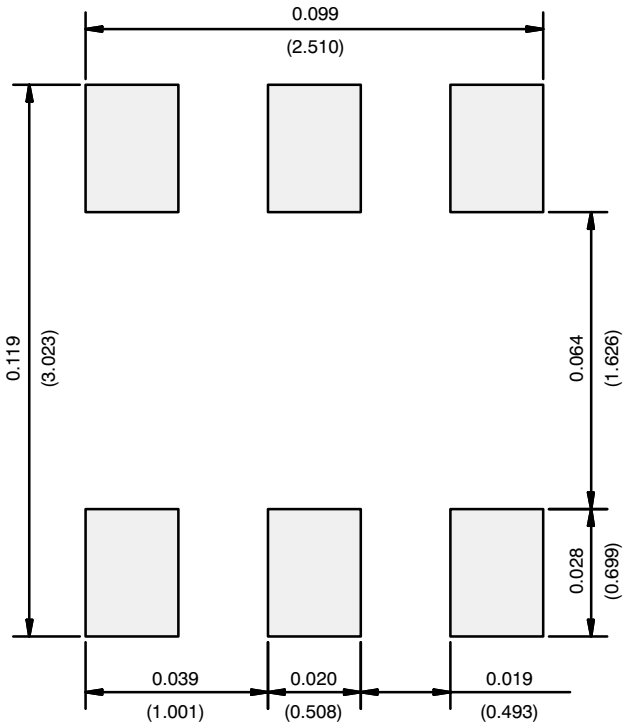




Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
A	0.91	-	1.10	0.036	-	0.043
A_1	0.01	-	0.10	0.0004	-	0.004
A_2	0.90	-	1.00	0.035	0.038	0.039
b	0.30	0.32	0.45	0.012	0.013	0.018
c	0.10	0.15	0.20	0.004	0.006	0.008
D	2.95	3.05	3.10	0.116	0.120	0.122
E	2.70	2.85	2.98	0.106	0.112	0.117
E_1	1.55	1.65	1.70	0.061	0.065	0.067
e	0.95 BSC			0.0374 BSC		
e_1	1.80	1.90	2.00	0.071	0.075	0.079
L	0.32	-	0.50	0.012	-	0.020
L_1	0.60 Ref			0.024 Ref		
L_2	0.25 BSC			0.010 BSC		
R	0.10	-	-	0.004	-	-
θ	0°	4°	8°	0°	4°	8°
$θ_1$	7° Nom			7° Nom		
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540						

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RECOMMENDED MINIMUM PADS FOR TSOP-6



Recommended Minimum Pads
Dimensions in Inches/(mm)

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